

Bipolar Transistor

**-160 V, -1.5 A, Low $V_{CE(sat)}$ PNP
Single LFPAK**

NST1601CL

This device is bipolar junction transistor featuring high current, low saturation voltage, and high speed switching.

Suitable for automotive applications. AEC-Q101 qualified and PPAP capable. (NSVT1601CLTWG)

Features

- Complement to NST1602CL
- Large Current Capacitance
- Low Collector to Emitter Saturation Voltage
- Thin Profile LFPAK8 3.3 x 3.3 mm Package
- High-Speed Switching
- High Allowable Power Dissipation
- AEC-Q101 Qualified and PPAP Capable (NSVT1601CLTWG)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Load Switch
- Gate Driver Buffer
- DC-DC Converters

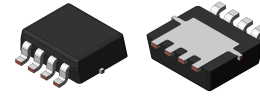
Specifications

ABSOLUTE MAXIMUM RATING at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Value	Unit
Collector to Base Voltage	V_{CBO}	-180	V
Collector to Emitter Voltage	V_{CEO}	-160	V
Emitter to Base Voltage	V_{EBO}	-6	V
Collector Current	I_C	-1.5	A
Collector Current (Pulse)	I_{CP}	-2.5	A
Collector Dissipation	P_C (Note 1)	0.8	W
	P_C (Note 2)	2.2	
Junction Temperature	T_j	175	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +175	$^\circ\text{C}$

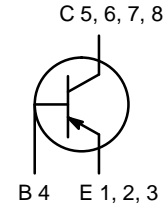
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Mounted on FRB with minimum pad of Copper 2 oz
2. Mounted on FRB with 1 in/sq pad of Copper 2 oz

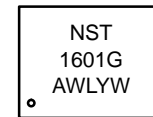


LFPAK8 3.3x3.3, 0.65P
CASE 760AD

ELECTRICAL CONNECTION



MARKING DIAGRAM



- NST1601 = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
W = Work Week
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NST1601CL

ELECTRICAL CHARACTERISTICS at Ta = 25°C

Parameter	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Collector Cutoff Current	ICBO	V _{CB} = -180 V I _E = 0 A	-	-	-0.1	μA
Emitter Cutoff Current	IEBO	V _{EB} = -6 V I _C = 0 A	-	-	-0.1	μA
DC Current Gain	hFE1	V _{CE} = -5 V I _C = -100 mA	140	-	280	
	hFE2	V _{CE} = -5 V I _C = -500 mA	130	-	-	
Gain-Bandwidth Product	f _T	V _{CE} = -10 V I _C = -100 mA	-	87	-	MHz
Output Capacitance	C _{ob}	V _{CB} = -10 V f = 1 MHz	-	19	-	pF
Collector to Emitter Saturation Voltage	V _{CE(sat)1}	I _C = -250 mA I _B = -25 mA	-	-0.08	-0.16	V
	V _{CE(sat)2}	I _C = -250 mA I _B = -50 mA	-	-0.06	-0.12	V
	V _{CE(sat)3}	I _C = -500 mA I _B = -50 mA	-	-0.1	-0.2	V
Base to Emitter Saturation Voltage	V _{BE(sat)}	I _C = -250 mA I _B = -25 mA	-	-0.8	-1.2	V
Collector to Base Breakdown Voltage	V(BR)CBO	I _C = -10 μA, I _E = 0 A	-180	-	-	V
Collector to Emitter Breakdown Voltage	V(BR)CEO	I _C = -1 mA, R _{BE} = ∞	-160	-	-	V
Emitter to Base Breakdown Voltage	V(BR)EBO	I _E = -10 μA, I _C = 0 A	-6	-	-	V
Turn-On Time	t _{on}	See Figure 1	-	50	-	ns
Storage Time	t _{stg}		-	1150	-	ns
Fall Time	t _f		-	40	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

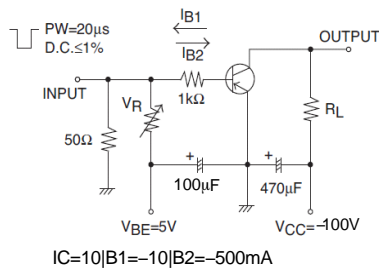


Figure 1. Switching Time Test Circuit

ESD RATING

Parameter	Symbol	Value	Unit	Class
Electrostatic Discharge –Human Body Model	HBM	>2000, <4000	V	Class 2
Electrostatic Discharge –Machine Model	MM	>400	V	Class M4

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TYPICAL CHARACTERISTICS

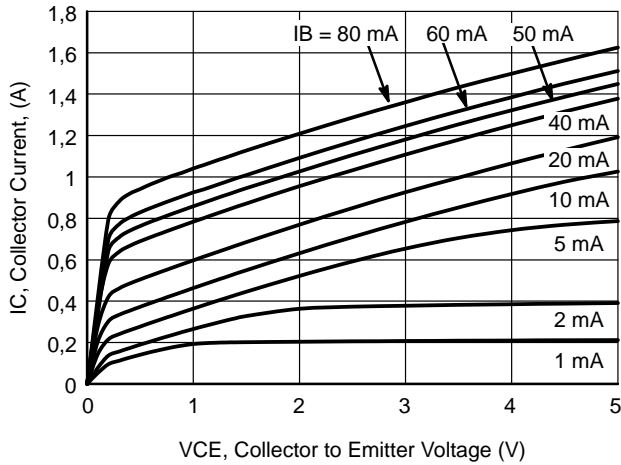


Figure 2. IC – VCE

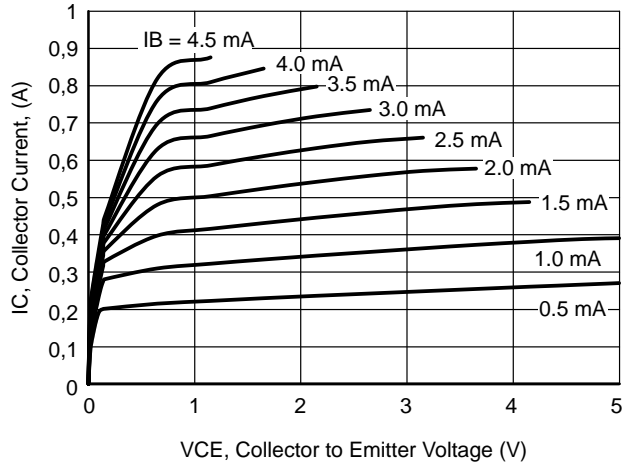


Figure 3. IC – VCE

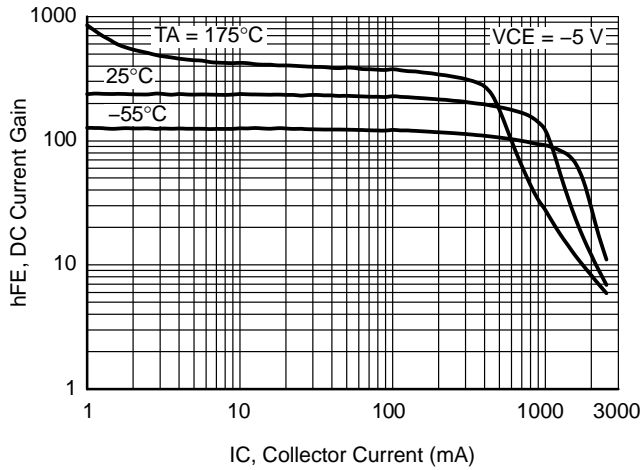


Figure 4. hFE – IC

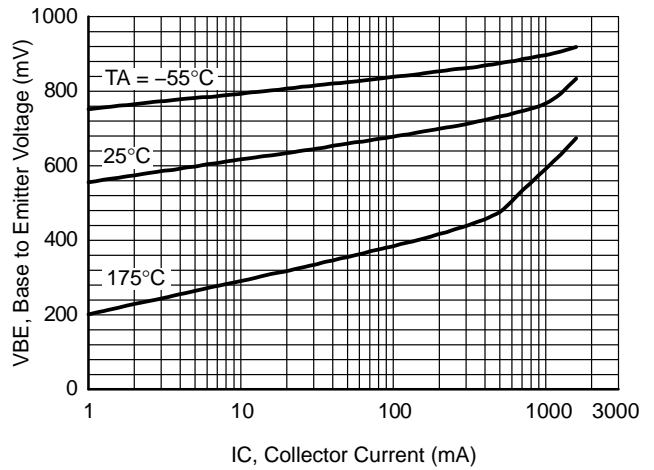


Figure 5. VBE – IC

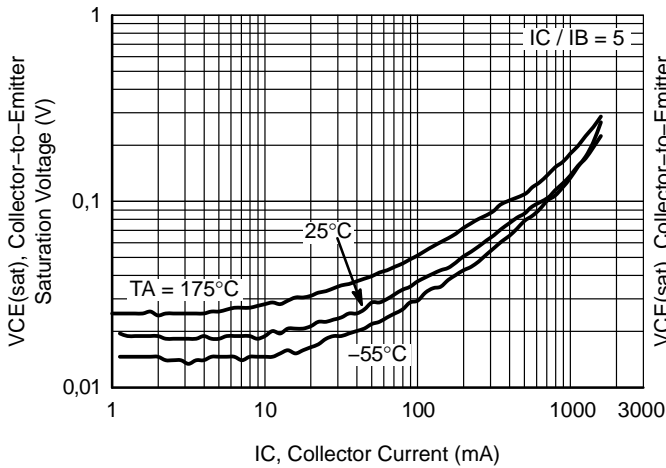


Figure 6. VCE(sat) – IC

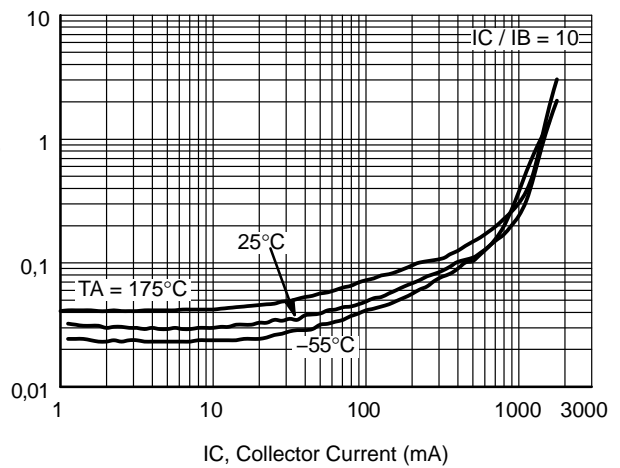


Figure 7. VCE(sat) – IC

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TYPICAL CHARACTERISTICS

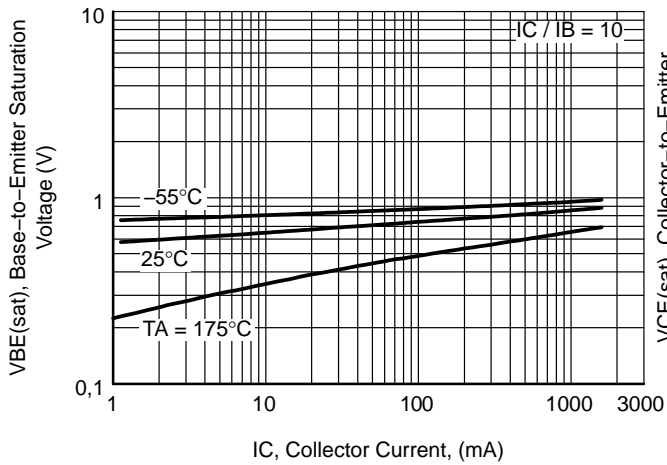


Figure 8. VBE(sat) – IC

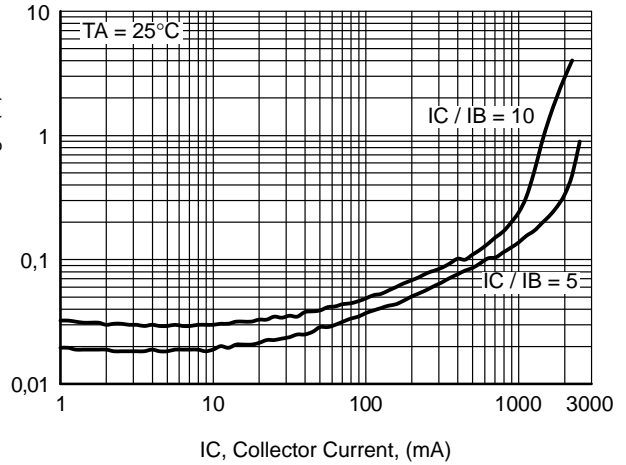


Figure 9. VCE(sat) – IC

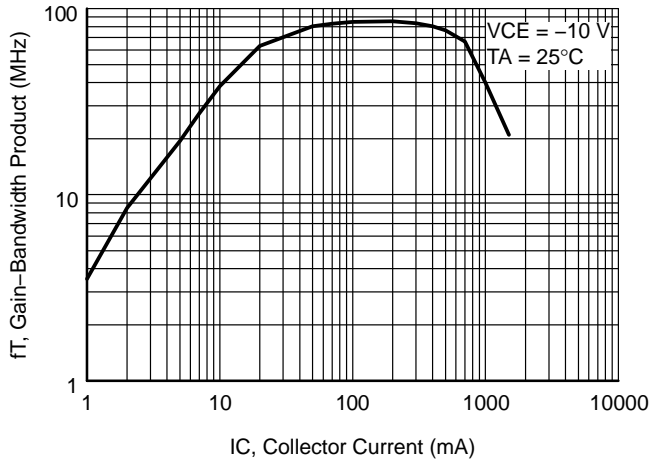


Figure 10. fT – IC

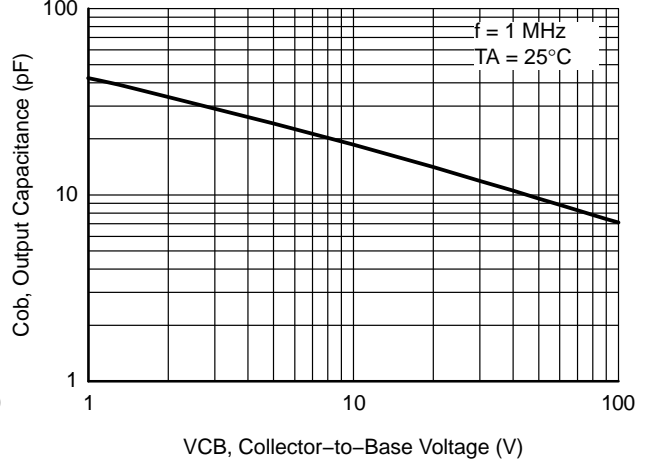


Figure 11. Cob – VCB

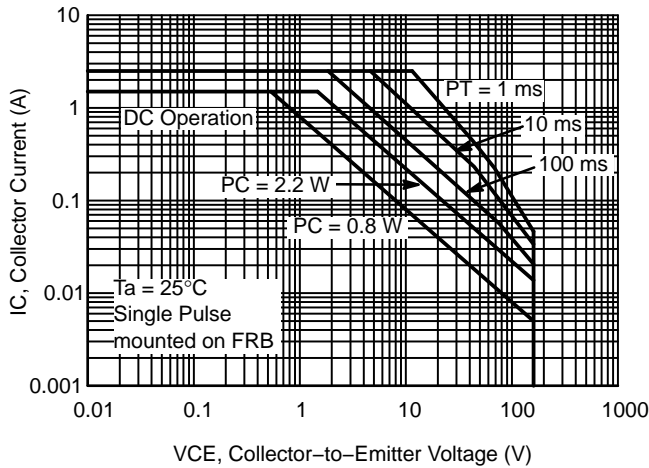


Figure 12. Safe Operating Area

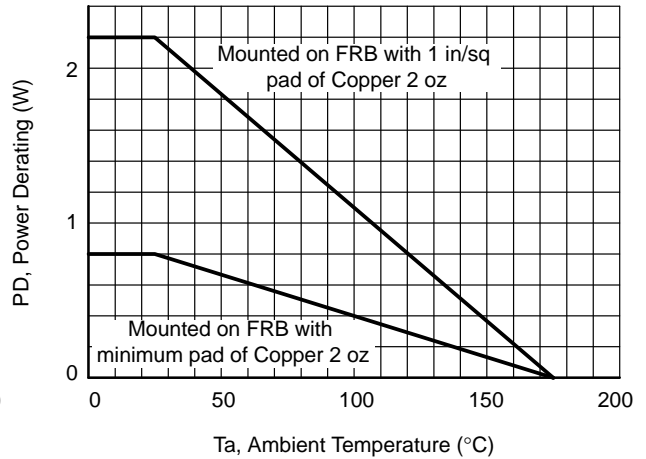


Figure 13. Power Derating

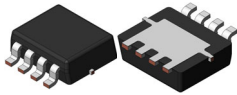
NST1601CL

ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing) [†]
NSVT1601CLTWG	NST1601G	LFPAK8 (Pb-Free / Halogen Free)	3,000 / Tape & Reel
NST1601CLTWG	NST1601G	LFPAK8 (Pb-Free / Halogen Free)	3,000 / Tape & Reel

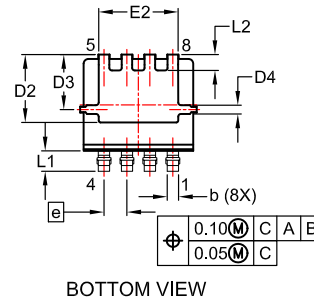
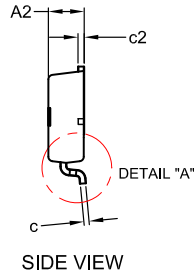
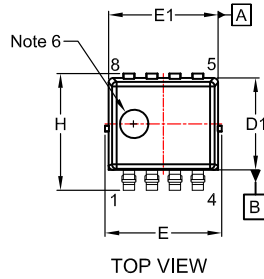
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

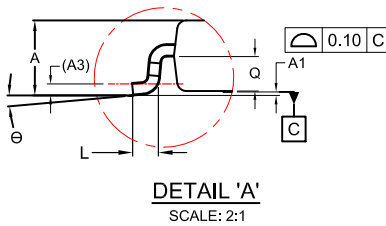


LFPAK8 3.3x3.3, 0.65P CASE 760AD ISSUE E

DATE 16 NOV 2020

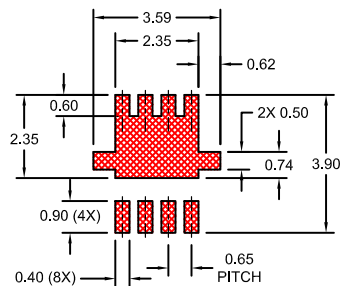


DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.95	1.05	1.15
A1	0.00	0.05	0.10
A2	0.95	1.00	1.05
A3	0.15 REF		
b	0.27	0.32	0.37
c	0.12	0.17	0.22
c2	0.12	0.17	0.22
D1	2.50	2.60	2.70
D2	1.82	1.92	2.02
D3	1.46	1.56	1.66
D4	0.20	0.25	0.30
E	3.20	3.30	3.40
E1	3.00	3.10	3.20
E2	2.15	2.25	2.35
e	0.65 BSC		
H	3.20	3.30	3.40
L	0.25	0.37	0.50
L1	0.48	0.58	0.68
L2	0.35	0.45	0.55
Q	0.45	0.50	0.55
θ	0°	4°	8°



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS OR BURRS SHALL NOT EXCEED 0.150mm PER SIDE.
4. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
5. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
6. OPTIONAL MOLD FEATURE.



*FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXX = Specific Device Code
 A = Assembly Location
 WL = Wafer Lot
 Y = Year
 W = Work Week

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "μ", may or may not be present. Some products may not follow the Generic Marking.

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